

**FEATURES**

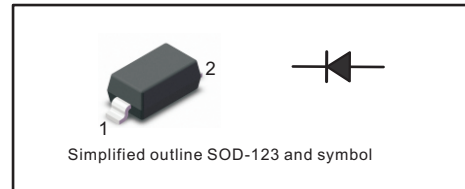
- For surface mounted applications
- Glass Passivated Chip Junction
- Fast reverse recovery time
- Ideal for automated placement
- Lead free in comply with EU RoHS 2011/65/EU directives

**MECHANICAL DATA**

- Case: SOD-123
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 16mg/0. 00056oz

**PINNING**

PIN	DESCRIPTION
1	Cathode
2	Anode


**Absolute Maximum Ratings at 25 °C**

Parameter	Symbols	BAV19W	BAV20W	BAV21W	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	120	200	250	V
Maximum RMS voltage	$V_{RMS}$	100	150	200	V
Continuous Forward Current	$I_F$	250			mA
Repetitive Peak Forward Current	$I_{FRM}$	625			mA
Non-repetitive Peak Forward Surge Current at 1s at 1ms at 1 us	$I_{FSM}$	1 3 9			A
Total Power Dissipation	$P_{tot}$	500			mW
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150			°C

**Characteristics at  $T_a = 25\text{ °C}$** 

Parameter	Symbols	BAV19W	BAV20W	BAV21W	Units
Reverse Breakdown Voltage at $I_R = 100\mu A$	$V_{(BR)R}$	120	200	250	V
Maximum Forward Voltage at 100 m A at 200 m A	$V_F$	1.00 1.25			V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25\text{ °C}$ $T_a = 150\text{ °C}$	$I_R$	0.1 100			$\mu A$
Typical Junction Capacitance at $V_R = 4V, f = 1MHz$	$C_j$	5			pF
Maximum Reverse Recovery Time <sup>(1)</sup>	$t_{rr}$	50			ns

( 1 ) Measured with  $I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A$



Fig.1 Power Derating Curve

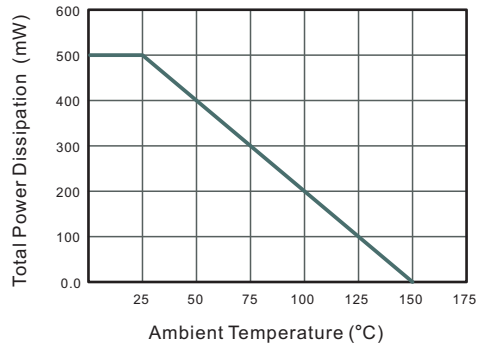


Fig.2 Typical Reverse Characteristics

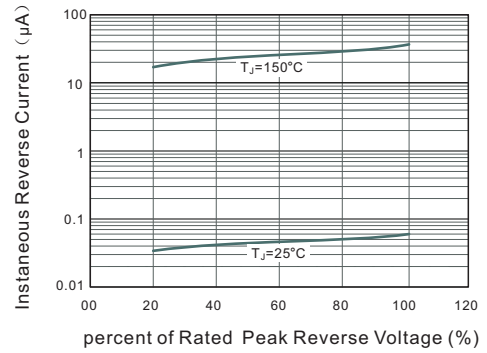


Fig.3 Typical Instantaneous Forward Characteristics

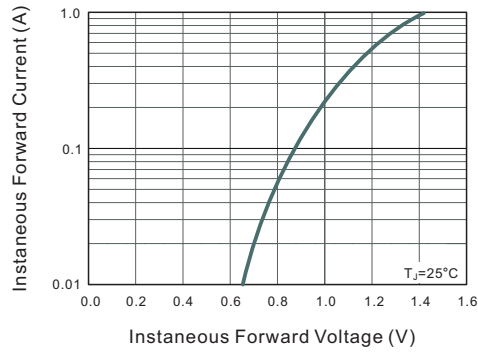
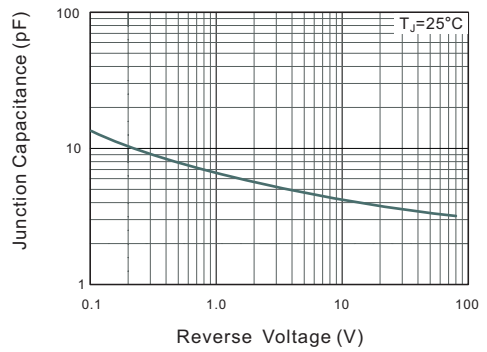


Fig.4 Typical Junction Capacitance

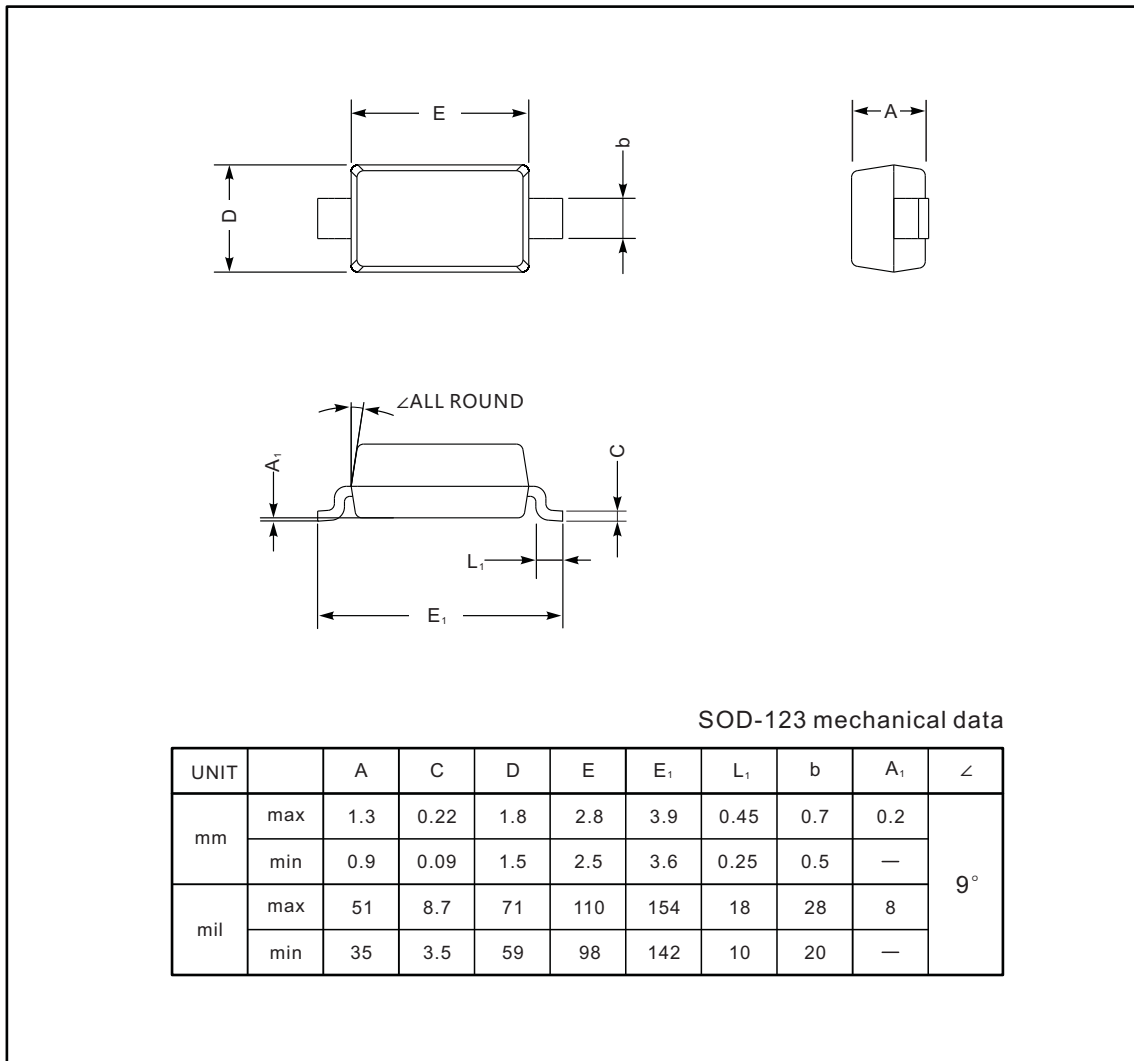




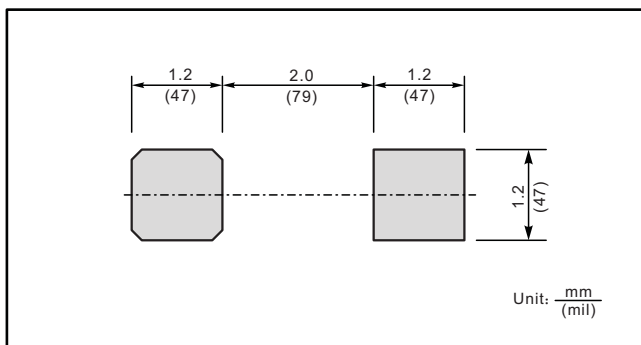
**PACKAGE OUTLINE**

Plastic surface mounted package; 2 leads

SOD-123



**The recommended mounting pad size**



**Marking**

Type number	Marking code
BAV19W	A8
BAV20W	T2
BAV21W	T3